Docket:	PATENT
COMBINED DECLARATION AND POWER OF ATTORNEY	
(ORIGINAL, DESIGN, NATIONAL STAGE OF PCT, SUPPLEMENTAL, DI CONTINUATION OR CIP)	VISIONAL,
As a below named inventor, I hereby declare that:	
TYPE OF DECLARATION	
This declaration is of the following type: (check one applicable item below)	
x original design supplemental	
Note: If the Declaration is for an International Application being filed as a division continuation-in-part application, do <u>not</u> check next item; check appropriate one of	nal, continuation or last three items.
national stage of PCT	
Note: If one of the following 3 items apply, then complete and also attach ADI DIVISIONAL, CONTINUATION OR CIP.	DED PAGES FOR
divisional	
continuation continuation-in-part (CIP)	
INVENTORSHIP IDENTIFICATION	
WARNING: If the inventors are each not the inventors of all the claims, an explanation of the ownership of all the claims at the time the last claimed invention was submitted.	the facts, including s made, should be
My residence, post office address and citizenship are as stated below, next believe that I am the original, first and sole inventor (if only one name is list original, first and joint inventor (if plural names are listed below) of the subje- claimed, and for which a patent is sought on the invention entitled:	ed below) or on
TITLE OF INVENTION	
SHARED DELAY CIRCUIT OF A SEMICONDUCTOR DEVICE	

SPECIFICATION IDENTIFICATION

the specification of which: (complete (a), (b) or (c))
x (a) is attached hereto.
(b) was filed on as Serial No or Express Mail No. (as Serial No. not yet known) and was amended on (if applicable).
Note: Amendments filed after the original papers are deposited with the PTO that contain new matter are not accorded a filing date by being referred to in the Declaration. Accordingly, the amendments involved are those filed with the application papers or, in the case of a supplemental Declaration, are those amendments claiming matter not encompassed in the original statement of invention or claims. See 37 CFR 1.67.
(c) was described and claimed in PCT International Application No filed on and as amended under PCT Article 19 on (if any).
ACKNOWLEDGEMENT OF REVIEW OF PAPERS AND DUTY OF CANDOR
I hereby state that I have reviewed and understand the contents of the above-identified specification, including the claims, as amended by any amendment referred to above.
I acknowledge the duty to disclose information, which is material to patentability as defined in 37, Code of Federal Regulations, § 1.56,
(also check the following items, if desired)
and which is material to the examination of this application, namely, information where there is a substantial likelihood that a reasonable Examiner would consider it important in deciding whether to allow the application to issue as a patent, and
in compliance with this duty, there is attached an information disclosure statement, in accordance with 37 CFR 1.98.
PRIORITY CLAIM (35 U.S.C. º 119(a)-(d))
I hereby claim foreign priority benefits under Title 35, United States Code, § 119(a)-(d) of any foreign application(s) for patent or inventor's certificate or of any PCT international application(s) designating at least one country other than the United States of America listed below and have also identified below any foreign application(s) for patent or inventor's certificate or any PCT international application(s) designating at least one country other than

the United States of America filed by me on the same subject matter having a filing date

before that of the application(s) of which priority is claimed.

(complete (d) or (e))

AND ANY PR	N/PCT APPLICATION(S IS FOR DESIGN) PRIC RIORITY CLAIMS UNDI	S) FILED TO THIS	S APPLICATION	THS
COUNTRY (OR INDICATE IF PCT	APPLICATION NUMBER		OF FILING nonth/year)	PRIORITY CLAIMED UNDER 35 USC 119
Republic of Korea	2003-38747	16/	/06/2003	⊠ YES NO □
				YES NO
I hereby claim the benef provisional application(s	lt under Title 35, Un) listed below: L APPLICATION N			(e) of any United States NG DATE
ALL FOREIGN APPLI (6 MONTHS F	ICATION(S), IF ANY FOR DESIGN) PRIOR T	, FILED M	ORE THAN 12 M	ONTHS ON

DECLARATION AND POWER OF ATTORNEY FOR DIVISIONAL, CONTINUATION OR CIP APPLICATION for benefit of the prior U.S. or PCT application(s) under 35 U.S.C. § 120.

POWER OF ATTORNEY

I hereby appoint the following practitioner(s) to prosecute this application and transact all business in the Patent and Trademark Office connected therewith (list name and registration number).

Thomas F. Peterson, 24790; Richard J. Streit, 25765; Donald P. Reynolds, 26220; W. Dennis Drehkoff, 27193; Vangelis Economou, 32341; Brian W. Hameder, 45613; Valerie Neymeyer-Tynkov, Reg. 46956; Paul B. West, 18947; Joseph H. Handelman, 26179; Peter D. Galloway 27885; John Richards, 31503; Iain C. Baillie, 24090; Richard P. Berg, 28145

Attached, as part of this declaration and power of attorney, is the authorization of the above-named practitioner(s) to accept and follow instructions from my representative(s).

SEND CORRESPONDENCE TO:

DIRECT TELEPHONE CALLS TO:

(Name and telephone number)

Richard J. Streit c/o Ladas & Parry 224 South Michigan Avenue Suite 1200 Chicago, Illinois 60604

(312) 427-1300

DECLARATION

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code, and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

SIGNATURE(S)

Note: Carefully indicate the family (or last) name, as it should appear on the filing receipt and all other documents.

Full name of sole or first inventor

Sang Hee	KANG		
(Given Name)	(Middle Initial or Name) (Family (or Last) No		
Inventor's signature	Sang-Hee Kang	- ' '	
Date September 16, 2003	Country of Citizenshi	ip Republic of Korea	
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